

Form PTO-1449		ATTY. DOCKET NO. 3430-0200P	APPLICATION NO. NEW 10/757521
INFORMATION DISCLOSURE CITATION IN AN APPLICATION <small>(Use several sheets if necessary)</small>		APPLICANT Woong-Kwon KIM	
		FILED DATE January 15, 2003	GROUP Unassigned

## U.S. PATENT DOCUMENTS

GRANTING INITIAL	DOCUMENT NUMBER	KIND	DATE	NAME	CLASS	END CLASS	FILED DATE 19 APPROPRIATE
	US 5,994,721	A	1999-11-30	ZHONG et al			
TM 12-2000 DC	US 6,104,510	A	12-2000	KASHIWAZAKI et al			
	US 6,104,459	A	2000-08-15	OIKE et al			
	US 5,724,107	A	1998-03-03	NISHIKAWA et al			
	US 6,211,928	B1	2001-04-03	OH et al			
	US 6,221,543	B1	2001-04-24	GUEHLER et al			
	US 5,994,721	A	1999-11-30	ZHONG et al			
	US 6,162,510	A	2000-12-19	KASHIWAZAKI et al			
	US 6,297,862	B1	2001-10-02	MURADE			
	US 6,166,786	A	2000-12-26	OHKUBO et al			
	US 6,327,006	B1	2001-12-04	SATO et al			
	US 6,281,955	B1	2001-08-28	MIDORIKAWA et al			
CL	US 6,111,623	A	2000-08-29	SATO			

## FOREIGN PATENT DOCUMENTS

Office	DOCUMENT NUMBER	Kind	DATE	COUNTRY	CLASS	END CLASS	TRANSLATION	
							YES	NO

OTHER DOCUMENTS (Include name of the author (in CAPITAL LETTERS), title of the article (when applicable), title of the item (book, magazine, journal, serial, organization, catalog, etc.) date, page(s), volume- issue number), publisher, city and/or country where published.)

<i>CL</i>	Pichon et al; "Low temperature unhydrogenated in-situ doped polysilicon thin film transistors: Toward a technology for flat panel displays"; Thin Solid Film, Vol. 296, pages 133-136, 1997.

EXAMINER <i>Hoan Nguyen</i>	DATE CONSIDERED <i>8/31/04</i>
EXAMINER: Initial if citations considered, otherwise or if citations do not conform to 37 C.F.R. 1.56. Enter "NO" if citations do not conform and not considered. Include copy of this form with next communication to applicant.	